

Notice of References Cited COPY	Application/Control No. 10/282,747	Applicant(s)/Patent Under Reexamination HARARI, ELIYAHOU	
	Examiner Viet Q Nguyen	Art Unit 2810 2828	Page 1 of 1

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	S				PRIMARY EXAMINER	
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V. Nguyen

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				M-12879 US		10/282,747	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Applicant			
(Use several sheets if necessary)				Eliyahou Harari			
COPY				Filing Date		Group	
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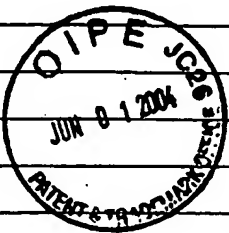
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